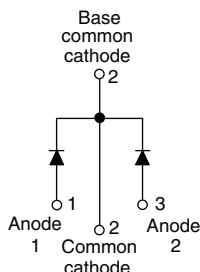


Ultrafast Rectifier, 2 x 35 A FRED Pt®


TO-218


FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Up to 175 °C operating junction temperature
- Common-cathode diodes
- Low leakage current
- Optimized for power conversion: welding and industrial SMPS applications
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level
- Halogen-free according to IEC 61249-2-21 definition



RoHS
COMPLIANT
HALOGEN
FREE

PRODUCT SUMMARY

Package	TO-218
$I_{F(AV)}$	2 x 35 A
V_R	200 V
V_F at I_F	1.09 V
t_{rr} typ.	See Recovery table
T_J max.	175 °C
Diode variation	Common cathode

DESCRIPTION

The VS-70CRU02PbF integrates two state of the art Vishay Semiconductors ultrafast recovery rectifiers in the common-cathode configuration. The planar structure of the diodes, and the platinum doping life-time control, provide a ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics. These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over-dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Continuous forward current per diode	$I_{F(AV)}$	$T_C = 145\text{ °C}$	35	A
Cathode to anode voltage	V_R		200	V
Single pulse forward current per diode	I_{FSM}	$T_C = 25\text{ °C}$	300	A
Maximum power dissipation per module	P_D	$T_C = 100\text{ °C}$	67	W
Operating junction and storage temperatures	T_J, T_{Stg}		- 55 to 175	°C

ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 60\text{ }\mu\text{A}$	200	-	-	V
Forward voltage	V_F	$I_F = 35\text{ A}$	-	0.95	1.09	
		$I_F = 35\text{ A}, T_J = 125\text{ °C}$	-	0.9	1.0	
		$I_F = 35\text{ A}, T_J = 175\text{ °C}$	-	0.85	0.9	
Reverse leakage current	I_R	$V_R = V_R$ rated	-	-	60	μA
		$T_J = 150\text{ °C}, V_R = V_R$ rated	-	-	2	mA
Junction capacitance	C_T	$V_R = 200\text{ V}$	-	50	-	pF
Series inductance	L_S	Measured from A-lead to K-lead 5 mm from package body	-	10	-	nH

DYNAMIC RECOVERY CHARACTERISTICS PER DIODE (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 1 A V _R = 30 V dI _F /dt = 200 A/μs	-	-	28	ns
		T _J = 125 °C		-	34	-	
		T _J = 25 °C	I _F = 35 A V _R = 100 V dI _F /dt = 200 A/μs	-	26	-	
		T _J = 125 °C		-	49	-	
Peak recovery current	I _{RRM}	T _J = 25 °C	I _F = 35 A V _R = 100 V dI _F /dt = 200 A/μs	-	3.7	-	A
		T _J = 125 °C		-	8.2	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	48.7	-	μC
		T _J = 125 °C		-	202	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R_{thJC}		-	0.8	0.9	K/W
			-	-	0.45	
Thermal resistance, case to heatsink	R_{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	
Weight			-	5.5	-	g
			-	0.2	-	oz.
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style TO-218	70CRU02			

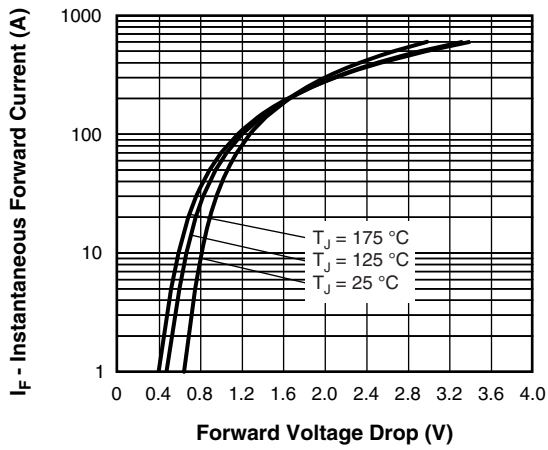


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Diode)

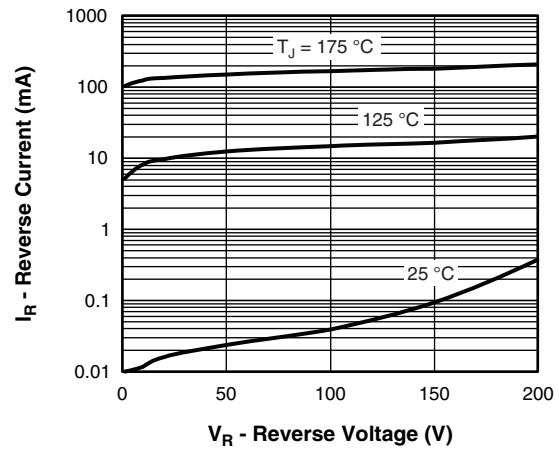


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

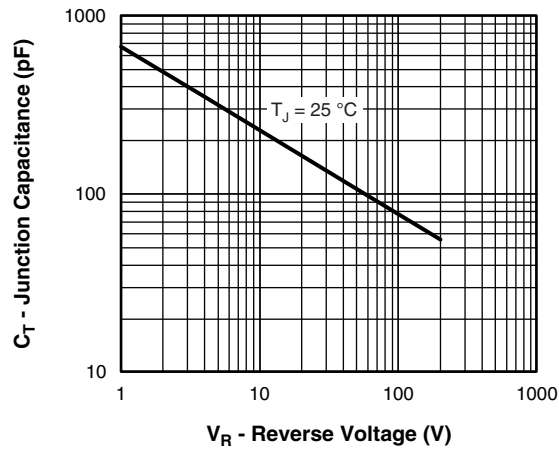
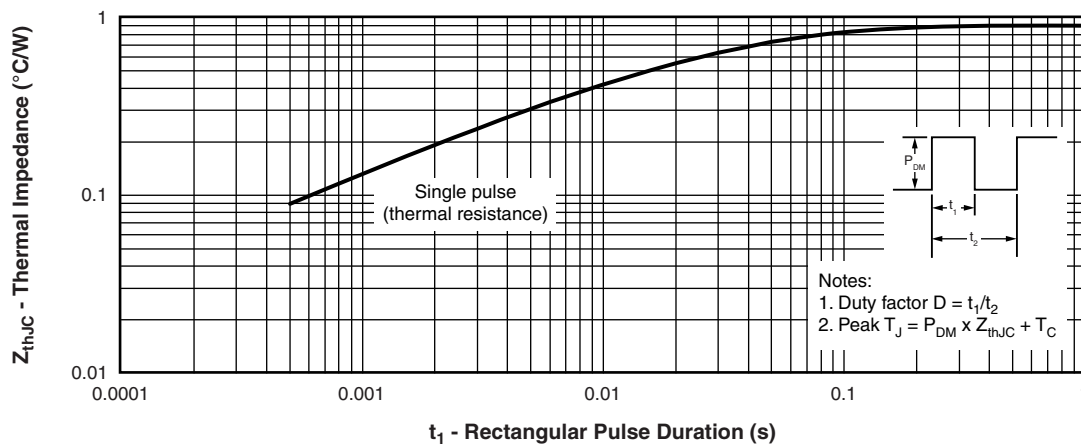


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage


 Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)

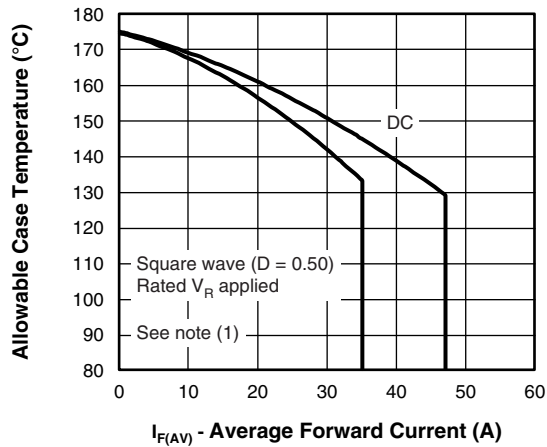


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

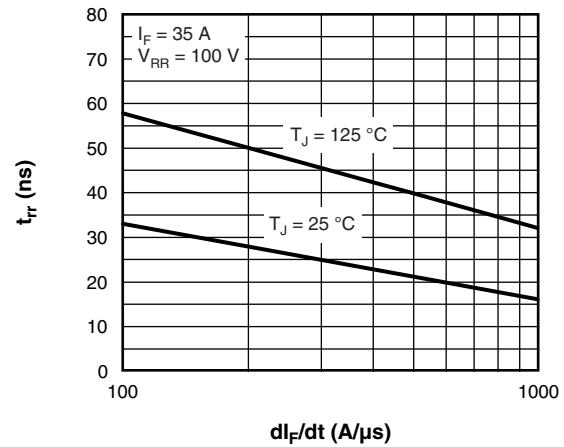


Fig. 7 - Typical Reverse Recovery Time vs. di_F/dt

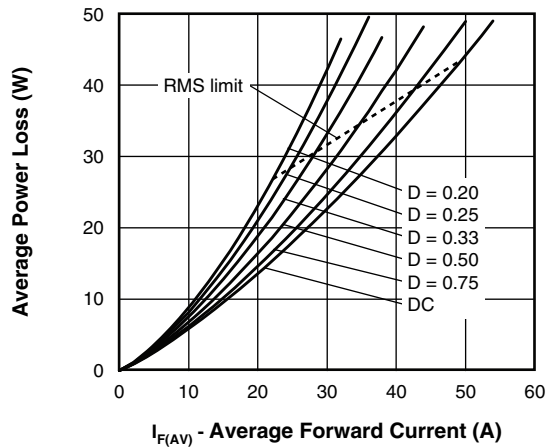


Fig. 6 - Forward Power Loss Characteristics

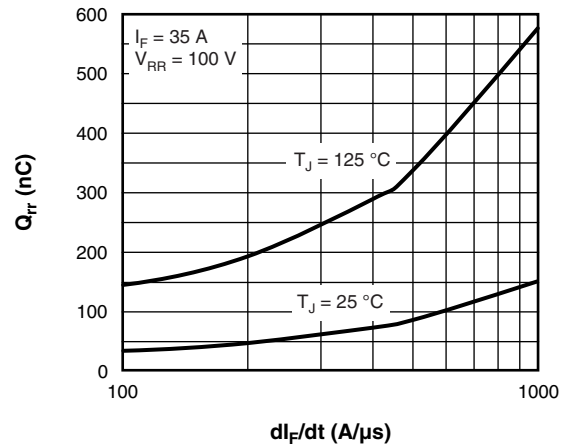


Fig. 8 - Typical Stored Charge vs. di_F/dt

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

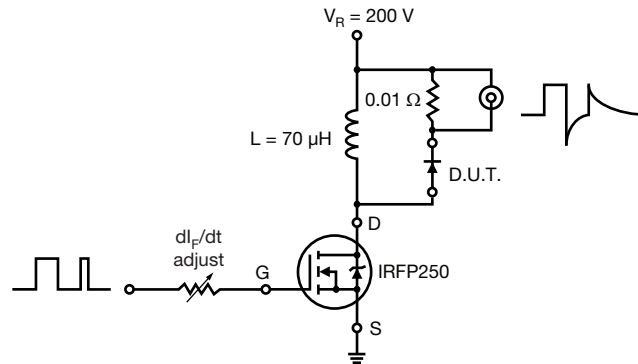


Fig. 9 - Reverse Recovery Parameter Test Circuit

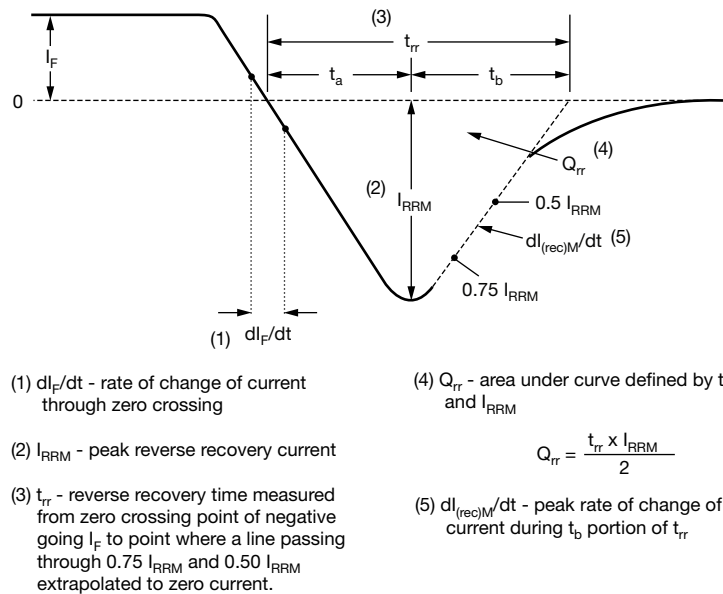


Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code	VS-	70	C	R	U	02	PbF
	1	2	3	4	5	6	7

- 1** - Vishay Semiconductors product
- 2** - Current rating (70 = 70 A)
- 3** - Common cathode
- 4** - TO-218
- 5** - Ultrafast recovery
- 6** - Voltage rating (02 = 200 V)
- 7** - PbF = Lead (Pb)-free

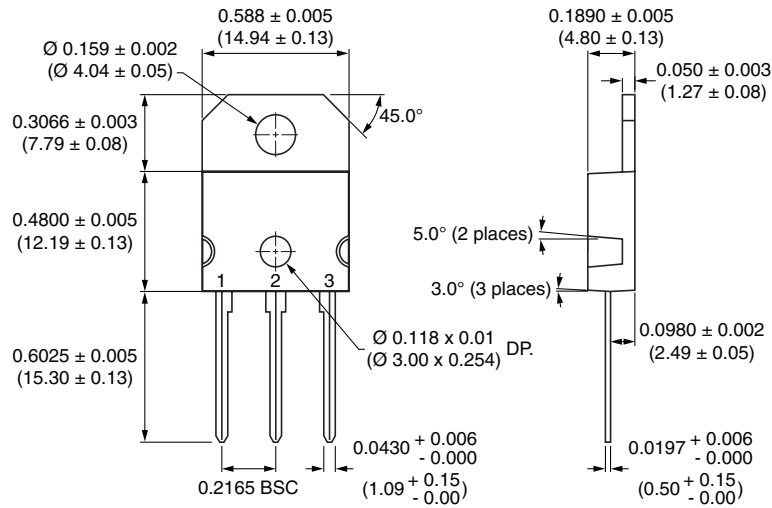
Tube standard pack quantity: 30 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95214
Part marking information	www.vishay.com/doc?95219



FRED Pt™ TO-218

DIMENSIONS in millimeters (inches)





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